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描述 / Descriptions

SOT-23 塑封封装 N 沟道 MOS 场效应管。N-CHANNEL MOSFET in a SOT-23 Plastic Package.

特征 / Features

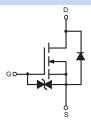
灵敏的控制级触发电流和很低的维持电流。静电保护达 2KV。无卤产品。 Sensitive gate trigger current and Low Holding current.ESD protected up to 2KV.HF Product.

用途 / Applications

用作一般的开关和相位控制。

Intended for use in general purpose switching and phase control applications.

内部等效电路 / Equivalent Circuit



引脚排列 / Pinning



PIN1: G PIN2: S PIN3: D

印章代码 / Marking

Marking	702K2
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极限参数 / Absolute Maximum Ratings(Ta=25°C)

参数	符号	数值	单位
Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DSS}	60	V
Drain-Gate Voltage	V_{DGR}	60	V
Drain Current - Continuous	I _D	300	mA
Drain Current - Pulsed(Note 1)	I _{DM}	1200	mA
Gate-Source Voltage - Continuous	V_{GSS}	±20	V
Power Dissipation	P _D	350	mW
Storage Temperature Range	T _{stg}	<i>-</i> 55∼150	${\mathbb C}$

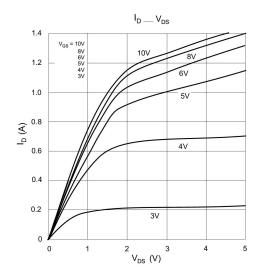
Note 1) Pulse Width10us, Duty Cycle □ 1%

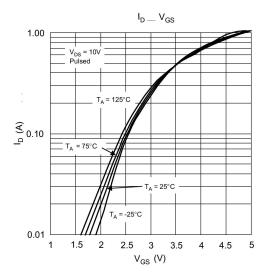
电性能参数 / Electrical Characteristics(Ta=25°C)

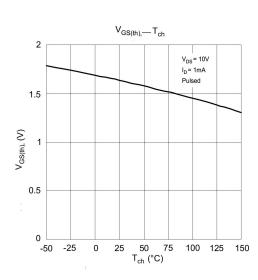
				1			
参数	符 号	测试条件		最小值	典型值	最大值	单位
Parameter	Symbol	Test Conditions		Min	Тур	Max	Unit
Drain–Source Breakdown Voltage	V_{DSS}	V _{GS} =0 I _D =10μA		60			V
Zero Gate Voltage Drain Current	I_{DSS}	V _{GS} =0	V_{DS} =60 V			1.0	μΑ
Gate-Source Leakage	I_{GSS}	V _{DS} =0V	V_{GS} = $\pm 20V$			±10	μΑ
Static Drain-Source On-Resistance	R _{DS(on)(1)}	V _{GS} =10V	I _D =0.5A			2.3	Ω
Static Dialii-Source Off-Resistance	$R_{DS(on)(2)}$	V _{GS} =5V	I _D =0.05A		1.7	2.7	Ω
Drain-Source Diode Forward Voltage	V_{SD}	V _{GS} =0V	I _S =250mA			1.5	٧
Drain-Source Diode Forward Voltage	$V_{GS(th)}$	V _{DS} =V _{GS}	I _D =250uA	1.0	1.6	2.5	V
Forward Transconductance	Y_{fs}	V _{DS} =10V	I _D =0.2A	80			mS
Drain Source On Voltage	$V_{DS(on)(1)}$	V _{GS} =10V	I_D =500mA			2.5	٧
Drain-Source On-Voltage	$V_{DS(on)(2)}$	V _{GS} =5.0V	I _D =50mA			0.275	٧
Turn-On Time	$t_{d(on)}$	V _{DD} =25V	I _D =500 mA			20	ns
Turn-Off Time	$t_{d(off)}$	R_G =25Ω V_{gen} =10V	$R_L=25\Omega$			40	ns
Input Capacitance	C _{iss}					50	pF
Output Capacitance	C _{oss}	V _{ds} =25V f=1MHZ	V _{GS} =0V		_	25	pF
Reverse Transfer Capacitance	C _{rss}					5	pF

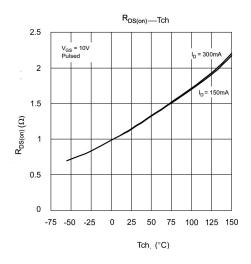


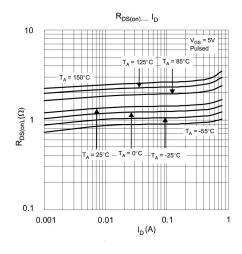
电参数曲线图 / Electrical Characteristic Curve

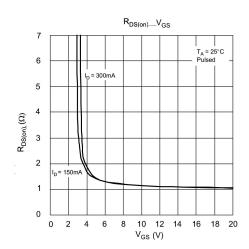












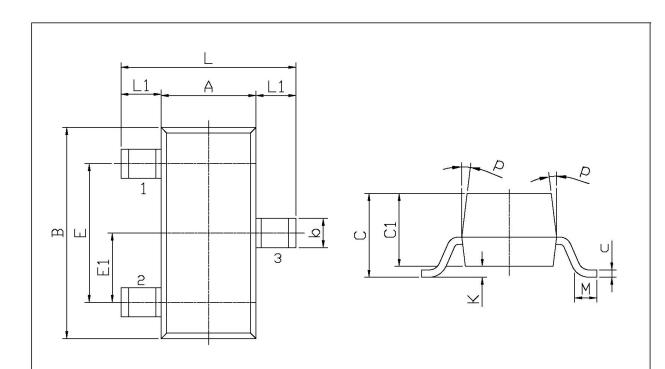
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外形尺寸图 / Package Dimensions

S0T-23

单位; mm

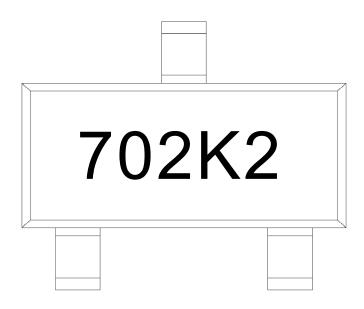


Symbol	Dimensions I	n Millmeters	C. mile al	Dimensions In Millmeters		
	Min	Max	Symbol	Min	Max	
L	ณ	2.7	С	1.30Ma×		
L1	0.45	0.65	C1	0.90	1.20	
Α	1,15	1.50	С	0.05	0.20	
В	2.70	3.10	К	0	0.10	
E	1.70	2.10	М	0,20MIN		
E1	0.85	1.05	Р	7°		
b	0.35	0,55				

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印章说明 / Marking Instructions



说明:

702K2: 为型号代码

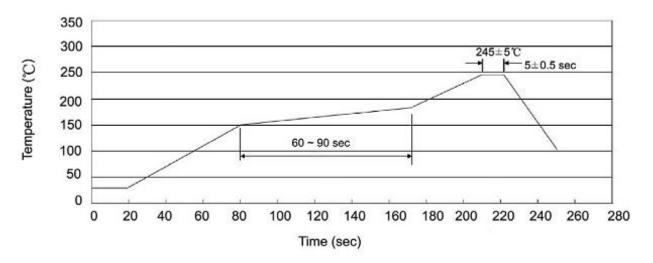
Note:

702K2: Product Type.

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回流焊温度曲线图(无铅) / Temperature Profile for IR Reflow Soldering(Pb-Free)



说明:

- 1、预热温度 150~180℃, 时间 60~90sec;
- 2、峰值温度 245±5℃, 时间持续为 5±0.5sec;
- 3、焊接制程冷却速度为 2~10℃/sec.

Note:

- 1.Preheating:150~180°C, Time:60~90sec.
- 2.Peak Temp.:245±5°C, Duration:5±0.5sec.
- 3. Cooling Speed: 2~10°C/sec.

耐焊接热试验条件 / Resistance to Soldering Heat Test Conditions

温度: 260±5℃ 时间: 10±1 sec. Temp.:260±5℃ Time:10±1 sec

包装规格 / Packaging SPEC.

卷盘包装 / REEL

Package Type	Units 包装数量				Dimension 包装尺寸 (unit: mm³)			
封装形式	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
SOT-23	3,000	10	30,000	6	180,000	7″ ×8	180×120×180	390×385×205

使用说明 / Notices